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Exam.Code:0906 Sub. Code: 7032

B.E. (Civil Engineering) Second Semester EC-201: Analog Electronic Circuits

		EC-201: Analog Electronic Circuits – I	
Time allowed: 3 Hours Max. 1			k. Marks: 50
NOTE:		five questions in all, including Question No. I which is ecting two questions from each Unit. $x-x-x$	
I.	Answe	er of the following:-	
	a)	Why is thermal stability in a transistor necessary?	(2)
	b)	What is the need for bias stabilization in Transistor Biasing?	(2)
	c)	Why are non-sinusoidal oscillators referred to as relaxation oscill	ators?(2)
	d)	State the Barkhausen criterion, i.e., the conditions necessary	for sinusoidal
		oscillations to be sustained.	(1)
	e)	What is heat sink?	(1)
	f)	Why transistor is called current controlled device?	(1)
	g)	What is distortion in power amplifiers?	(1)
		<u>UNIT – I</u>	
II.	refe	plain the input and output characteristics of a transistor in CE conference to early effect.	
II.	refe b) Cal		
II.	refe b) Cal valu a) Ob net	rence to early effect. culate I_c and I_E for a transistor that has $\alpha_{dc}=0.98$ and $I_B=100$	μA. Find the (6,4) as a two port
	a) Ob net and b) A to is s hie	rence to early effect. Iculate I_c and I_E for a transistor that has $\alpha_{dc} = 0.98$ and $I_B = 100$ are of β_{dc} of the transistor. Itain an expression in terms of 'h' parameters for a transistor awork. Using the above developed equations obtain the hybrid model of the stransistor of the	μ A. Find the (6,4) as a two port del of CE, CC, and of 10 kΩ. It are h_{ie} =1.1 kΩ,
	a) Obnet and b) A triss shie (iii	rence to early effect. Iculate I_c and I_E for a transistor that has $\alpha_{dc} = 0.98$ and $I_B = 100$ he of β_{dc} of the transistor. Itain an expression in terms of 'h' parameters for a transistor awork. Using the above developed equations obtain the hybrid model CB configuration. Transistor is connected as a common emitter amplifier driving a loss supplied by a source of 1 k Ω internal resistance. The 'h' parameter = 50, $h_{re} = 2.5 \times 10^{-4}$, $h_{oe} = 1/40 \text{ k}\Omega$. Find (i) current gain, (ii)	μ A. Find the (6,4) as a two port lel of CE, CC, and of 10 kΩ. It are h_{ie} =1.1 kΩ, Voltage gain, (5,5)
III.	a) Obnet and b) A triss shie (iii	rence to early effect. Iculate I_c and I_E for a transistor that has $\alpha_{dc} = 0.98$ and $I_B = 100$ he of β_{dc} of the transistor. Itain an expression in terms of 'h' parameters for a transistor awork. Using the above developed equations obtain the hybrid model CB configuration. Transistor is connected as a common emitter amplifier driving a load supplied by a source of 1 k Ω internal resistance. The 'h' parameter $= 50$, $h_{re} = 2.5 \times 10^{-4}$, $h_{oe} = 1/40 \text{ k}\Omega$. Find (i) current gain, (ii) input impedance, (iv) output impedance.	μ A. Find the (6,4) as a two port lel of CE, CC, and of 10 kΩ. It are h_{ie} =1.1 kΩ, Voltage gain, (5,5)

UNIT - II

- V. a) What is an Transformer coupled amplifier? Explain its working with the help of suitable diagram.
 - b) What is meant by bandwidth of an amplifier? What is its significance and how do you determine it in case of amplifier? (5,5)
- VI. a) With the help of relevant circuit diagram, describe the operation of Phase Shift Oscillator. What are the phase shifts introduced by the feedback and amplifier parts?
 - b) What are Crystal oscillators? What makes crystal oscillators exhibit exceptionally high frequency stability? (5,5)
- VII. a) What are Single tuned and double tuned amplifiers? What are the drawbacks of a single tuned amplifier?
 - b) What is Push Pull amplifier? Explain the functioning of a Class B push-pull power amplifier with necessary circuit diagram. (5,5)